Supporting Information

Anharmonic rattling leading ultra-low lattice thermal conductivity in Cu₁₂Sb₄S₁₃ tetrahedrites

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The Supporting Information includes structural, phonon dispersion relations, eigen vector visualizations, electrical, thermal and Raman spectroscopic measurements.

S1: Sound Velocity Measurement Details:

The mean sound velocity (v_m) was estimated from the longitudinal (v_l) and transverse (v_t) sound *velocities* via the formula:

The Grüneisen parameter (γ_G) was estimated using the formula:

Where, v_p is the Poisson ratio which is calculated from v_l and v_t through:

$$v_{p} = \frac{1 - 2\left(\frac{v_{t}}{v_{l}}\right)^{2}}{2 - 2\left(\frac{v_{t}}{v_{l}}\right)^{2}}, \dots \dots \dots \dots (3)$$

The Debye temperature (Θ_D) was calculated from the mean sound velocity (ν_m) using:

where h, N and V_u are the Planck's constant, number of atoms in a unit cell and unit-cell volume.¹

Further, the bulk (*B*) and shear modulus (*G*) were determined using the v_l , v_t and density (ρ) of the material using the equation:

S2: Lorenz number Calculations:

The Lorenz number (*L*) is calculated by fitting the reduced chemical potential (η), which is derived from the temperature dependent Seebeck coefficient, single parabolic band and acoustic phonon scattering,² via:

$$S = \frac{k_B}{e} \left(\frac{2F_1(\eta)}{F_0(\eta)} - \eta \right)_{.....(8)}$$

and
$$L = \left(\frac{k_B}{e} \right)^2 \frac{3F_0(\eta)F_2(\eta) - 4F_1^2(\eta)}{F_0^2(\eta)}_{....(9)}$$

 $\eta = \left(\frac{E_F}{k_B T}\right)_{\text{, in which } k_B \text{ being the Boltzmann's constant and the Fermi integral, } F_{n(\eta)}$

is denoted by:



Fig. S1 Rietveld refined XRD pattern of Cu₁₂Sb₄S₁₃ using Fullprof Suite software.



Fig. S2 The Cu(12*e*) atoms exhibit a large atomic displacement parameter (ADP: U_{eq}), with temperatures, in comparison with other atoms (Sb, S) and Cu(12*d*), for (a) without U (Coulombic interaction term) and (b) with U.



Fig. S3 The atom-projected phonon dispersion relation without U (Coulombic interaction term) for Cu₁₂Sb₄S₁₃.



Fig. S4 The atom-projected phonon dispersion relation with U (Coulombic interaction term) for Cu₁₂Sb₄S₁₃.



Fig. S5 The low energy acoustic and optical phonon interactions shown in green circle (a) without U parameter, and the purple rectangular box at Γ -point represents the negative modes frequencies, (b) with U parameter, for Cu₁₂Sb₄S₁₃, respectively.



Fig. S6 The eigen vector visualization of imaginary (unstable) vibrational modes, which strongly involves the dominating Cu(12e) atom vibrations (shown in purple arrow).



Fig. S7 Temperature dependent (a) 3-100 K, (b) 150-350 K, and (c) 400-550 K in the low-frequency (~15-75 cm⁻¹) Raman spectra fitting through Lorentzian function.



Fig. S8 Lorentzian function fitting of Raman active mode at 3 K, where the low frequency modes are clearly visible for $Cu_{12}Sb_4S_{13}$.



Fig. S9 The eigen vector visualization for low-frequency Raman active modes, which strongly involves the dominating vibrations of Cu(12*e*) atoms.



Fig. S10 The eigen vector visualization of highest intensive Raman active modes, which involves the dominating vibrations of Cu(12d), Sb(8c) and S(24g) atoms.



Fig. S11 Temperature dependent (3 – 550 K) phonon lifetime (τ_i) of prominent vibrational mode of Cu₁₂Sb₄S₁₃.



Fig. S12 The temperature dependent carrier concentration (n_H), plot for Cu₁₂Sb₄S₁₃.



Fig. S13 The (a) electronic band structure and (b) density of states for $Cu_{12}Sb_4S_{13}$ without U (Columbic interaction) term.



Fig. S14 The (a) electronic band structure and (b) density of states for $Cu_{12}Sb_4S_{13}$ with U (Columbic interaction) term.



Fig. S15 The convergence of valance band near the Fermi energy (E_f) level.



Fig. S16 Temperature dependence diffusivity (D) for $Cu_{12}Sb_4S_{13}$.



Fig. S17 The estimated Lorenz number (L) for $Cu_{12}Sb_4S_{13}$.

Table S1. The Rietveld refined crystal structure parameters for $Cu_{12}Sb_4S_{13}$.

$\begin{vmatrix} \mathbf{a} = \mathbf{b} = \mathbf{c} \\ (\mathbf{A}) \end{vmatrix} \mathbf{Cu}(12)$	<i>Cu</i> (12 <i>d</i>)	Sb(8 <i>c</i>)	S(2 <i>a</i>)	S(24g)	V(Å ³)
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10.3318	x = 0.25 y = 0.50 z = 0.00	x = 0.2108 y = 0.00 z = 0.00	x = 0.2665 y = 0.2665 z = 0.2665	x = 0.00 y = 0.00 z = 0.00	x = 0.1111 y = 0.1111 z = 0.3642	1102.8 9
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Table S2. The fitting parameters obtained from the heat capacity $(1D-3E \mod d)$ data.

Fitting parameters (1 <i>D</i> -3 <i>E</i>) model	$Cu_{12}Sb_4S_{13}$		
γ (J mol ⁻¹ K ⁻²)	$\sim 0.085 \pm 0.005$		
β (J mol ⁻¹ K ⁻⁴)	$\sim 4.28E-4 \pm 1.9E-5$		
A (J mol ⁻¹ K ⁻¹)	~ 11.3 ± 0.4		
$\Theta_{E1}(\mathbf{K})$	$\sim 24.7\pm0.3$		
B (J mol-1 K-1)	$\sim 98.0\pm 3.5$		
$\Theta_{E2}(\mathbf{K})$	$\sim 64.3\pm 0.8$		
C (J mol ⁻¹ K ⁻¹)	$\sim 238.8\pm2.5$		
$\Theta_{E3}(\mathbf{K})$	~ 123.7 ± 1.4		
R^2 (Adj. R-Square)	~0.9999		
χ^2 (Reduced Chi-Square)	1.03E-4		

References:

- 1. P. Acharyya, T. Ghosh, K. Pal, K. S. Rana, M. Dutta, D. Swain, M. Etter, A. Soni, U. V. Waghmare and K. Biswas, *Nature Communications*, 2022, **13**, 5053.
- K. Biswas, J. He, I. D. Blum, C.-I. Wu, T. P. Hogan, D. N. Seidman, V. P. Dravid and M. G. Kanatzidis, *Nature*, 2012, 489, 414-418.